

# IDH08SG60C

Data Sheet

Silicon Carbide Schottky Diodes - NEW 3G now available!; Package: PG-TO220-2; Technology: thinQ!<sup>TM</sup> 3G; V: 600.0 V; IF (typ): 8.0 A; QC (typ): 12.0 nC; Package: TO-220 real 2pin, Schottky Diodes SIC DIODEN

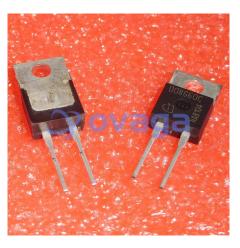
Manufacturers <u>Infineon Technologies Corporation</u>

Package/Case TO-220-2

Product Type Diodes & Rectifiers

RoHS Rohs

Lifecycle



Images are for reference only

Please submit RFQ for IDH08SG60C or Email to us: sales@ovaga.com We will contact you in 12 hours.

**RFO** 

## **General Description**

IDH08SG60C is a power module device manufactured by Infineon Technologies. It is a 600V, 8A Integrated Power Hybrid IC that includes an IGBT half-bridge and a driver circuit.

Features Application

Low power losses due to low VCEsat IGBTs and optimized driver

Motor control in industrial and home appliances

Low EMI due to the soft switching behavior of the IGBTs

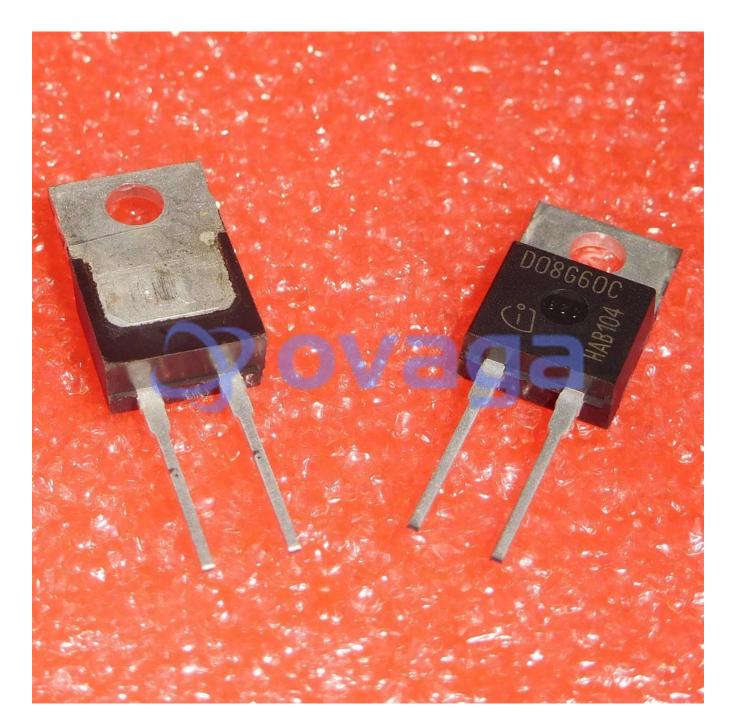
Switching power supplies

High ruggedness and reliability due to the integrated temperature and overcurrent protection Solar inverters

High power density due to the compact design

UPS and power backup systems

Welding machines



### **Related Products**



**IDB06S60C** 

Infineon Technologies Corporation D2PAK



**IDL12G65C5** 

Infineon Technologies Corporation
ThinPAK 8x8



IDH06SG60C

Infineon Technologies Corporation TO-220-2



IDL08G65C5

Infineon Technologies Corporation
ThinPAK 8x8



#### **IDL06G65C5**

Infineon Technologies Corporation
ThinPAK 8x8



#### <u>IDL04G65C5</u>

Infineon Technologies Corporation
ThinPAK 8x8



#### **IDK10G65C5**

Infineon Technologies Corporation D2PAK



#### **IDK06G65C5**

Infineon Technologies Corporation D2PAK